

BV _{CES}	400±30V
ا _C	30A
V _{CE(sat) (Typ.)}	1.6V
E _{AS}	300mJ

Features

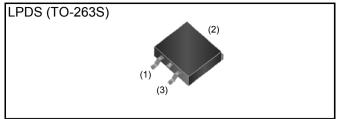
- 1) Low Collector Emitter Saturation Voltage
- 2) High Self-Clamped Inductive Switching Energy
- 3) Built in Gate-Emitter Protection Diode
- 4) Built in Gate-Emitter Resistance
- 5) Qualified to AEC-Q101
- 6) Pb free Lead Plating ; RoHS Compliant

Applications

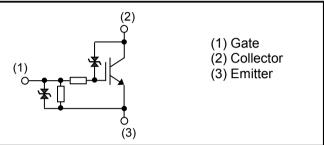
Ignition Coil Driver Circuits

Solenoid Driver Circuits

Outline



Inner Circuit



Packaging Specifications

	Packaging	Taping
	Reel Size (mm)	330
Tuno	Tape Width (mm)	24
Туре	Basic Ordering Unit (pcs)	1,000
	Packing Code	TL
	Marking	RGPR30NS40

•Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	430	V
Emitter-Collector Voltage (V _{GE} = 0)	/)	V _{EC}	25	V
Gate - Emitter Voltage		V _{GES}	±10	V
Collector Current		۱ _C	30	А
Avalanche Energy (Single Pulse)	$T_j = 25^{\circ}C$	E _{AS}	300	mJ
	T _j = 150°C	E _{AS} *2	180	mJ
Power Dissipation		P _D	125	W
Operating Junction Temperature		Tj	-40 to +175	°C
Storage Temperature		T _{stg}	–55 to +175	°C

•Thermal Resistance

Parameter	Symbol	Values			Unit
	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	R _{θ(j-c)}	-	-	1.20	°C/W

•Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Deremeter	Cumhal	Conditions		1.7 2.1 V 1.3 - V		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
		I _C = 2mA, V _{GE} = 0V				
Collector - Emitter Breakdown Voltage	BV_{CES}	T _j = 25°C	370	400	430	V
		$T_j = -40$ to $175^{\circ}C^{*2}$	365	-	435	V
Emitter - Collector Breakdown Voltage	BV _{EC}	I _C = –10mA, V _{GE} = 0V	25	35	-	V
Gate - Emitter Breakdown Voltage	BV_{GES}	$I_G = \pm 5 mA$, $V_{CE} = 0V$	±12	-	±17	V
		V _{CE} = 250V, V _{GE} = 0V				
Collector Cut - off Current	I _{CES}	$T_j = 25^{\circ}C$	-	-	7	μA
		$T_{j} = 150^{\circ}C^{*2}$	-	-	100	μA
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 10V, V_{CE} = 0V$	±0.4	±0.6	±1.2	mA
		V _{CE} = 5V, I _C = 12mA				
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	T _j = 25°C	1.3	1.7	2.1	V
		$T_{j} = 150^{\circ}C^{*2}$	-	1.3	-	V
		I _C = 12A, V _{GE} = 5V				
Collector - Emitter Saturation Voltage	$V_{CE(sat)}$	T _j = 25°C	-	1.60	2.00	V
5		T _j = 150°C	-	1.80	-	V
		I _C = 5A, V _{GE} = 4.5V				
Collector - Emitter Saturation Voltage	$V_{CE(sat)}$	T _j = 25°C	-	1.17	1.50	V
-		T _j = 150°C	-	1.19	-	V

•Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Devenuetor	C) maked	Conditions		Values		Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	
		I _C = 12A, V _{GE} = 4V				
Collector - Emitter Saturation Voltage	V _{CE(sat)}	T _j = 25°C	-	1.70	2.10	V
5		T _j = 150°C	-	1.90	-	V
Input Capacitance	C _{ies}	V _{CE} = 10V	-	1330	-	
Output Capacitance	C _{oes}	V _{GE} = 0V	-	220	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	71	-	
Total Gate Charge	Qg	V _{CE} = 12V, I _C = 10A, V _{GE} = 5V	-	22	-	nC
Turn - on Delay Time ^{*1,*2}	t _{d(on)}		0.11	0.19	0.50	
Rise Time ^{*1,*2}	t _r	$I_{\rm C} = 8A, V_{\rm CC} = 300V,$	0.10	0.18	0.50	
Turn - off Delay Time ^{*1,*2}	t _{d(off)}	V _{GE} = 5V, R _G = 100Ω, L=5mH, T _j =25°C	0.9	1.4	4.0	50 .0 .5
Fall Time ^{*1,*2}	t _f		0.8	1.8	5.5	
Turn - on Delay Time ^{*1}	t _{d(on)}		-	0.18	-	
Rise Time ^{*1}	t _r	I _C = 8A, V _{CC} = 300V, V _{GE} = 5V, R _G = 100Ω,	-	0.21	-	
Turn - off Delay Time ^{*1}	t _{d(off)}	L=5mH, T_j =150°C	-	1.7	-	μs
Fall Time ^{*1}	t _f		-	3.0	-	
	_	L = 5mH, V_{GE} = 5V, V_{CC} = 30V, R_G = 1k Ω ,				
Avalanche Energy (Single Pulse)	E _{AS}	T _j = 25°C	300	-	-	mJ
		$T_{j} = 150^{\circ}C^{*2}$	180	-	-	mJ
Gate Series Resistance	R _G		70	100	130	Ω
Gate - Emitter Resistance	R_{GE}		8	16	24	kΩ

*1) Assurance items according to our measurement definition (Fig.18)

*2) Design assurance items

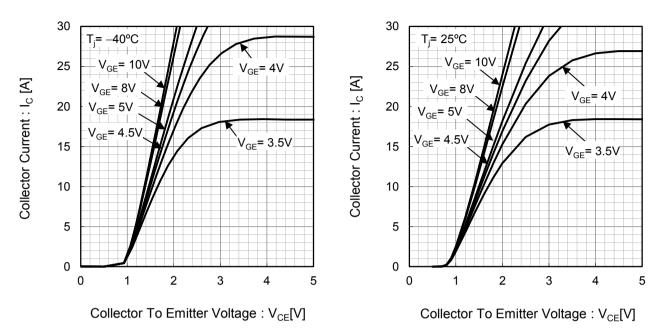
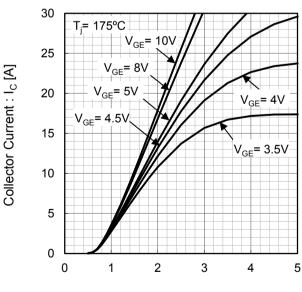


Fig.1 Typical Output Characteristics

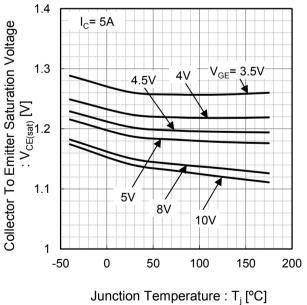
Fig.2 Typical Output Characteristics

Fig.3 Typical Output Characteristics



Collector To Emitter Voltage : $V_{CE}[V]$

Fig.4 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



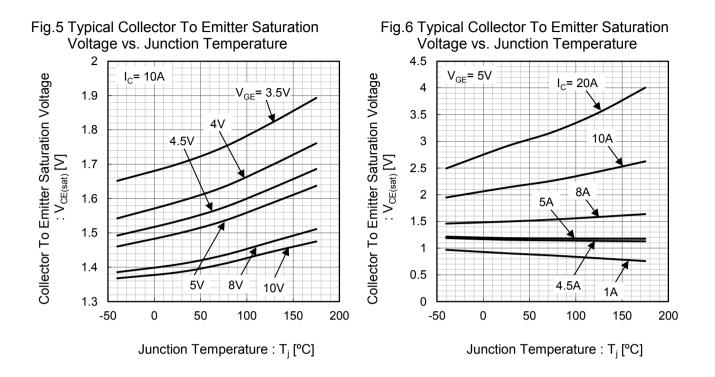
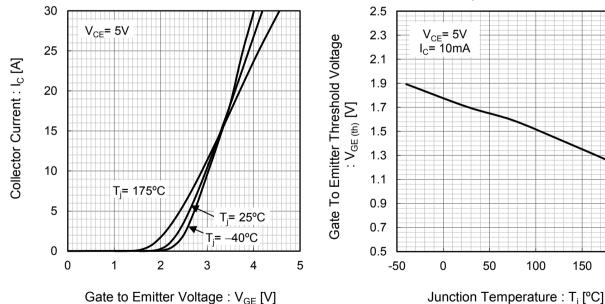


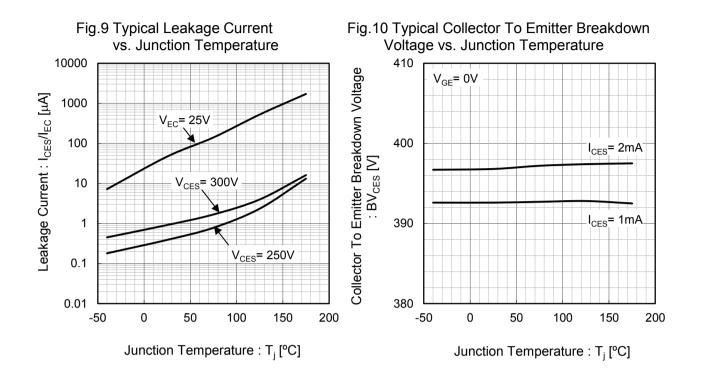
Fig.7 Typical Transfer Characteristics

Fig.8 Typical Gate To Emitter Threshold Voltage vs. Junction Temperature



150

200



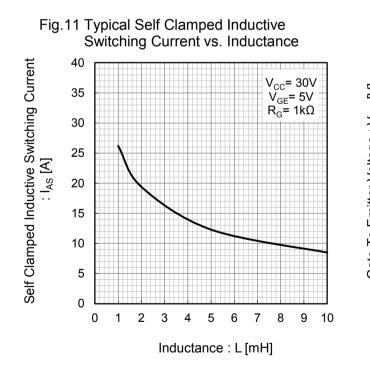
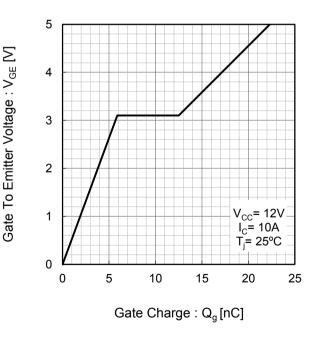


Fig.12 Typical Gate Charge



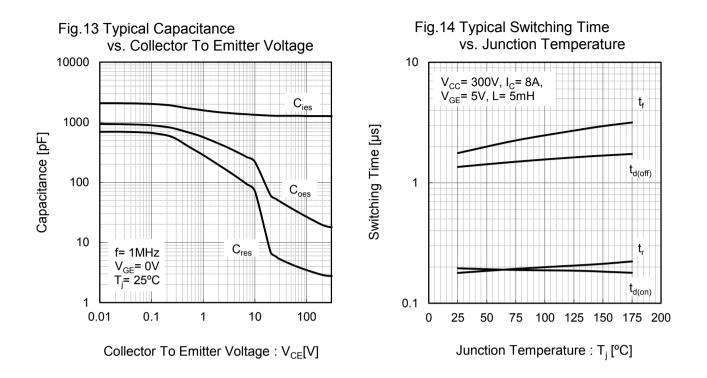
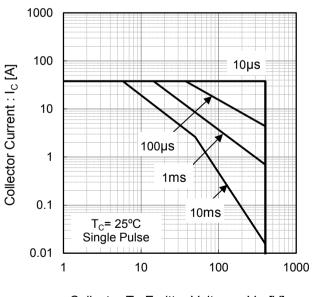


Fig.15 Forward Bias Safe Operating Area



Collector To Emitter	Voltage :	V _{CE} [V]
----------------------	-----------	---------------------

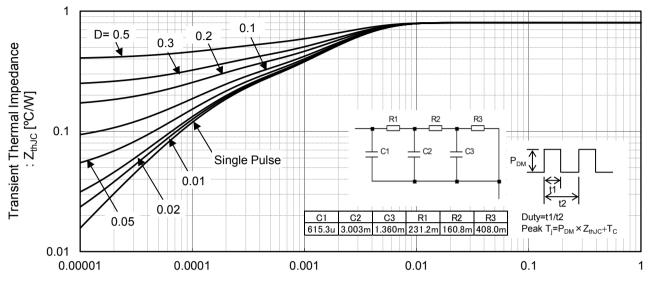


Fig.16 Transient Thermal Impedance

Pulse Width : t1[s]

Inductive Load Switching Circuit and Waveform

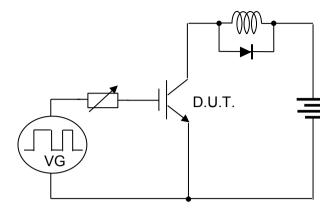


Fig.17 Inductive Load Switching Circuit

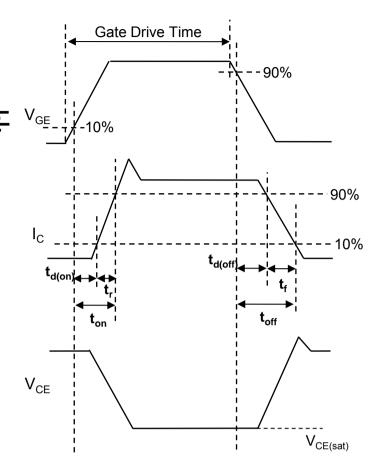


Fig.18 Inductive Load Switching Waveform

•Self Clamped Inductive Switching Circuit and Waveform

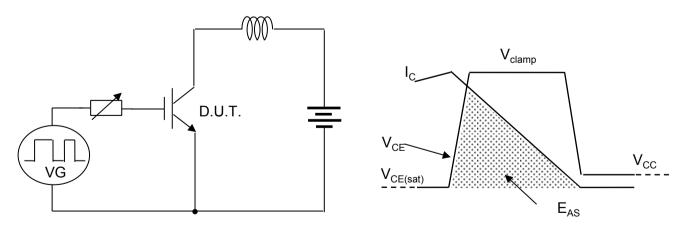


Fig.19 Self Clamped Inductive Switching Ciruit

Fig.20 Self Clamped Inductive Switching Waveform

	Notes
1)	The information contained herein is subject to change without notice.
2)	Before you use our Products, please contact our sales representative and verify the latest specifica- tions :
3)	Although ROHM is continuously working to improve product reliability and quality, semicon- ductors can break down and malfunction due to various factors. Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM.
4)	Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The periphera conditions must be taken into account when designing circuits for mass production.
5)	The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly any license to use or exercise intellectual property or other rights held by ROHM or any othe parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use o such technical information.
6)	The Products specified in this document are not designed to be radiation tolerant.
7)	For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative : transportation equipment (i.e cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.
8)	Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
9)	ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
10)	ROHM has used reasonable care to ensur the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
11)	Please use the Products in accordance with any applicable environmental laws and regulations such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
12)	When providing our Products and technologies contained in this document to other countries you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
13)	This document, in part or in whole, may not be reprinted or reproduced without prior consent o ROHM.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/